



Diagonal 8mm (Type 1/2) Progressive Scan CCD Image Sensor with Square Pixel for EIA B/W Video Cameras

Description

The ICX074AL is an interline CCD solid-state image sensor suitable for EIA black-and-white video cameras. Progressive scan allows all pixels signals to be output independently within approximately 1/60 second. This chip features an electronic shutter with variable charge-storage time which makes it possible to realize full-frame still image without mechanical shutter. Individual pixels in a square matrix make this device suitable for image input and processing applications.

High sensitivity and low dark current are achieved through the adoption of HAD (Hole-Accumulation Diode) sensors.

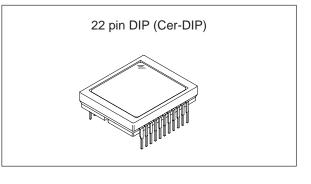
Features

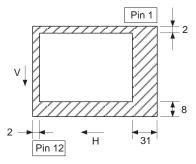
- Progressive scan allows individual readout of the image signals from all pixels.
- High vertical resolution (480TV-lines) still picture without mechanical shutter.
- Square pixel unit cell
- VGA format-compatible
- High resolution, high sensitivity, low dark current
- Continuous variable-speed shutter
- · Low smear
- Excellent antiblooming characteristics
- Reset gate: 5V drive (bias: no adjustment)

Device Structure

| Image size: | Diagonal 8mm (Type | 1/2) |
|---|--------------------------|----------------------------------|
| Number of effective pixels: | 659 (H) × 494 (V) | approx. 330K pixels |
| Total number of pixels: | 692 (H) × 504 (V) | approx. 350K pixels |
| Interline CCD image sensor | | |
| • Chip size: | 8.10mm (H) × 6.33mi | m (V) |
| Unit cell size: | 9.9µm (H) × 9.9µm (\ | /) |
| Optical black: | Horizontal (H) direction | on: Front 2pixels, rear 31pixels |
| | Vertical (V) direction: | Front 8pixels, rear 2pixels |
| Number of dummy bits: | Horizontal 16 | |
| | Vertical 5 | |
| Substrate material: | Silicon | |

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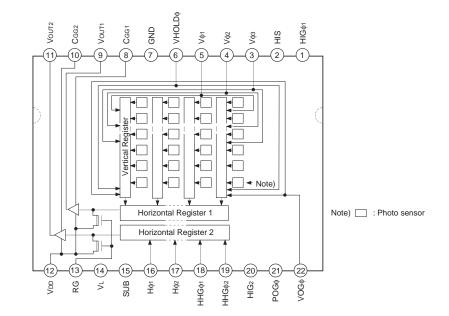




Optical black position (Top View)

Block Diagram and Pin Configuration

(Top View)



Pin Description

| Pin No. | Symbol | Description | Pin No. | Symbol | Description |
|------------|--------|--|------------|--------------------|--|
| 1 | HIGφ1 | Test pin *2 | 12 | Vdd | Supply voltage |
| 2 | HIS | Test pin *2 | 13 | RG | Reset gate clock |
| 3 | Vфз | Vertical register transfer clock | 14 | VL | Protective transistor bias |
| 4 | Vø2 | Vertical register transfer clock | 15 | SUB | Substrate (overflow drain) |
| 5 | Vφ1 | Vertical register transfer clock | 16 | Hφ1 | Horizontal register transfer clock |
| 6 | VHOLDø | Vertical register final stage accumulation clock | 17 | Ηφ2 | Horizontal register transfer clock |
| 7 | GND | GND | 18 | HHGφ1 | Inter-horizontal register transfer clock |
| 8 | CGG1 | Output amplifier 1 gate *1 decoupling capacitor | 19 | HHG _{\$2} | Inter-horizontal register transfer clock |
| 9 | Vout1 | Signal output 1 | 20 | HIG ₂ | Test pin *2 |
| 10 | CGG2 | Output amplifier 2 gate *1 decoupling capacitor | 21 | POGø | Test pin *2 |
| 11 | Vout2 | Signal output 2 | 22 | VOGø | Vertical register final stage transfer clock |

*1 DC bias is applied within the CCD, so that this pin should be grounded externally through a capacitance of 1µF or more.

*2 Regarding the test pins: apply the same voltage as the supply voltage to HIS, and ground HIGφ₁, HIG₂, and POGφ.

Absolute Maximum Ratings

| | Item | Ratings | Unit | Remarks |
|-----------------------------|--|---------------|------|---------|
| Substrate voltage SUB – G | ND | -0.3 to +55 | V | |
| Supply voltage | VDD, VOUT1, VOUT2, HIS, CGG1, CGG2 – GND | -0.3 to +18 | V | |
| Supply voltage | VDD, VOUT1, VOUT2, HIS, CGG1, CGG2 – SUB | -55 to +10 | V | |
| | Vφ1, Vφ2, Vφ3, VHOLDφ, VOGφ – GND | -15 to +20 | V | |
| Clock input voltage | V ϕ_1 , V ϕ_2 , V ϕ_3 , VHOLD ϕ , VOG ϕ – SUB | to +10 | V | |
| Voltage difference between | to +15 | V | *1 | |
| Voltage difference between | to +17 | V | | |
| Ηφ1, Ηφ2 – VOGφ | | -17 to +17 | V | |
| Ηφ1, Ηφ2 – GND | | -10 to +15 | V | |
| Ηφ1, Ηφ2 – SUB | | -55 to +10 | V | |
| VL – SUB | | -65 to +0.3 | V | |
| Vφ2, Vφ3, Vdd, Vout1, Vout2 | , HIS, HIGφ1, HIG2, POGφ – VL | -0.3 to +27.5 | V | |
| RG – GND | | -0.3 to +22.5 | V | |
| Vφ1, Cgg1, Cgg2, Hφ1, Hφ2, | -0.3 to +17.5 | V | | |
| Storage temperature | -30 to +80 | °C | | |
| Operating temperature | | -10 to +60 | °C | |

*1 +27V (Max.) when clock width < 10 μ s, clock duty factor < 0.1%.

Bias Conditions

| Item | Symbol | Min. | Тур. | Max. | Unit | Remarks |
|--|--------|---------------------------|----------------------|---------------------------|------|---------|
| Supply voltage | Vdd | 14.55 | 15.0 | 15.45 | V | |
| Substrate voltage adjustment range | Vsuв | 9.0 | | 18.5 | V | *1 |
| Substrate voltage adjustment precision | | Indicated voltage –0.1 | Indicated voltage | Indicated voltage +0.1 | V | |
| Protective transistor bias | VL | | *2 | | | |

DC Characteristics

| Item | Symbol | Min. | Тур. | Max. | Unit | Remarks |
|----------------|--------|------|------|------|------|---------|
| Supply current | Idd | | 10 | | mA | |
| Input current | Iin1 | | | 1 | μA | *3 |
| Input current | lin2 | | | 10 | μA | *4 |

*1 Indications of substrate voltage (Vsub) setting value

The setting value of the substrate voltage is indicated on the back of image sensor by a special code. Adjust the substrate voltage (Vsub) to the indicated voltage.

Vsub code — two characters indication

| \uparrow | |
|------------|--|

 \square

Integer portion Decimal portion

The integer portion of the code and the actual value correspond to each other as follows.

| Integer portion of code | 9 | Α | С | d | Е | f | G | h | J | К |
|-------------------------|---|----|----|----|----|----|----|----|----|----|
| Value | 9 | 10 | 11 | 12 | 13 | 14 | 15 | 16 | 17 | 18 |

<Example> "A5" \rightarrow Vsub = 10.5V.

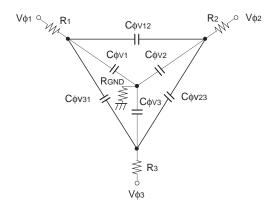
- *2 VL setting is the VvL voltage of the vertical transfer clock waveform, or the same power supply as the VL power supply for the V driver should be used.
- *3 (1) Current to each pin when 18V is applied to VDD, VOUT1, VOUT2, HIS, RG, CGG1, CGG2, GND and SUB pins, while pins that are not tested are grounded.
 - (2) Current to each pin when 20V is applied sequentially to Vφ1, Vφ2 and Vφ3 pins, while pins that are not tested are grounded. However, 20V is applied to SUB pin.
 - (3) Current to each pin when 15V is applied sequentially to RG, Hφ1 and Hφ2 pins, while pins that are not tested are grounded. However, 15V is applied to SUB pin.
 - (4) Current to VL pin when 25V is applied to Vφ2, Vφ3, POGφ, HIGφ1, HIG2, VDD, VOUT1 and VOUT2 pins or when, 15V is applied to Vφ1, VHOLDφ, VOGφ, CGG1, CGG2, Hφ1, Hφ2, HHGφ1 and HHGφ2 pins, while VL pin is grounded. However, GND and SUB pins are left open.
 - (5) Current to GND pin when 20V is applied to the RG pin and the GND pin is grounded.
- *4 Current to SUB pin when 55V is applied to SUB pin, while all pins that are not tested are grounded.

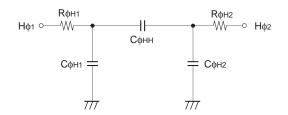
Clock Voltage Conditions

| Item | Symbol | Min. | Тур. | Max. | Unit | Waveform diagram | Remarks |
|--|------------------|-------------|-------------|-------------|------|---------------------|-------------------------------------|
| Readout clock voltage | Vvт | 14.55 | 15.0 | 15.45 | V | 1 | |
| | Vvh02 | -0.05 | 0 | 0.05 | V | 2 | Vvh = Vvho2 |
| | Vvh1, Vvh2, Vvh3 | -0.2 | 0 | 0.05 | V | 2 | |
| | VVL1, VVL2, VVL3 | -8.0 | -7.5 | -7.0 | V | 2 | $V_{VL} = (V_{VL01} + V_{VL03})/2$ |
| | Vφv | 6.8 | 7.5 | 8.05 | V | 2 | $V\phi = VvHn - VvLn (n = 1 to 3)$ |
| Vertical transfer clock voltage | I Vvl1 – Vvl3 I | | | 0.1 | V | 2 | |
| | Vvнн | | | 0.5 | V | 2 | High-level coupling |
| | Vvhl | | | 0.5 | V | 2 | High-level coupling |
| | Vvlh | | | 0.5 | V | 2 | Low-level coupling |
| | Vvll | | | 0.5 | V | 2 | Low-level coupling |
| Horizontal transfer | Vфн | 4.75 | 5.0 | 5.75 | V | 3 | |
| clock voltage | Vhl | -0.05 | 0 | 0.05 | V | 3 | |
| | Vørg | 4.5 | 5.0 | 5.5 | V | 4 | Input through 0.01µF capacitance |
| Reset gate clock voltage | Vrglh – Vrgll | | | 0.8 | V | 4 | Low-level coupling |
| | Vrgh | Vdd +0.4 | Vdd +0.6 | Vdd +0.8 | V | 4 | |
| Substrate clock voltage | Vфsuв | 21.5 | 22.5 | 23.5 | V | 5 | |
| Vertical final stage accumulation clock voltage | Vvholdh, Vvogh | -0.05 | 0 | 0.05 | V | 6 | |
| transfer clock voltage | Vvholdl, Vvogl | -8.0 | -7.5 | -7.0 | V | 6 | |
| | Vннд1н, Vннд2н | 4.75 | 5.0 | 5.25 | V | 7 | |
| Inter-horizontal register transfer clock voltage | Vhhg1l, Vhhg2l | -8.0 | -7.5 | -7.0 | V | 7 | |
| | Vннд1м, Vннд2м | -0.05 | 0 | 0.05 | V | 7 | |

Clock Equivalent Circuit Constant

| Item | Symbol | Min. | Тур. | Max. | Unit | Remarks |
|---|--------------|------|------|------|------|---------|
| | C¢V1 | | 3300 | | pF | |
| Capacitance between vertical transfer clock and GND | C φV2 | | 4700 | | pF | |
| | Сфvз | | 4700 | | pF | |
| | СфV12 | | 1000 | | pF | |
| Capacitance between vertical transfer clocks | Сфv23 | | 22 | | pF | |
| | Сф∨з1 | | 100 | | pF | |
| Capacitance between vertical final stage accumulation clock and GND | Сфуногр | | 19 | | pF | |
| Capacitance between vertical final stage transfer clock and GND | Сфиод | | 12 | | pF | |
| Capacitance between inter-horizontal | Сфннд1 | | 23 | | pF | |
| register transfer clock and GND | Сфннд2 | | 19 | | pF | |
| Capacitance between horizontal transfer | Сфн1 | | 60 | | pF | |
| clock and GND | Сфн2 | | 69 | | pF | |
| Capacitance between horizontal transfer clocks | Сфнн | | 40 | | pF | |
| Capacitance between reset gate clock and GND | Сфр | | 9 | | pF | |
| Capacitance between substrate clock and GND | Сфѕив | | 400 | | pF | |
| Vertical transfer clock series resistor | R1, R2, R3 | | 10 | | Ω | |
| Vertical transfer clock ground resistor | Rgnd | | 15 | | Ω | |
| | Rфн1 | | 24 | | Ω | |
| Horizontal transfer clock series resistor | Rфн2 | | 30 | | Ω | |



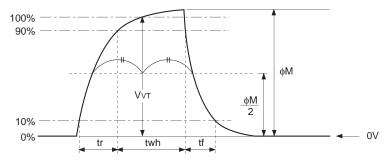


Vertical transfer clock equivalent circuit

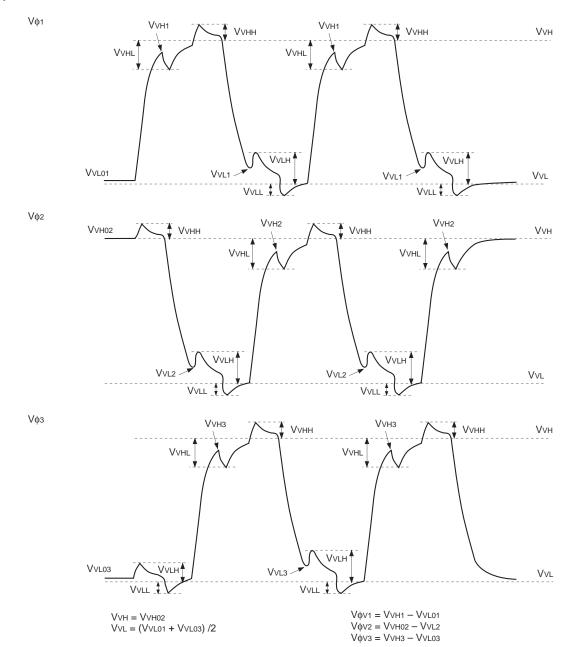


Drive Clock Waveform Conditions

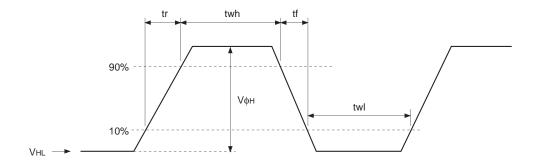
(1) Readout clock waveform



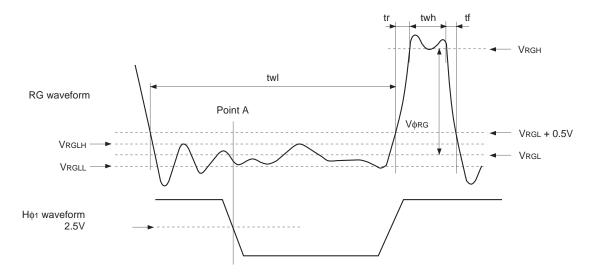
(2) Vertical transfer clock waveform



(3) Horizontal transfer clock waveform



(4) Reset gate clock waveform



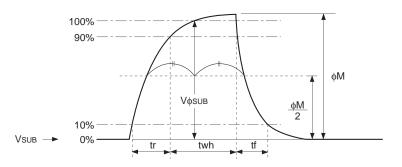
VRGLH is the maximum value and VRGLL is the minimum value of the coupling waveform during the period from Point A in the above diagram until the rising edge of RG. In addition, VRGL is the average value of VRGLH and VRGLL.

VRGL = (VRGLH + VRGLL)/2

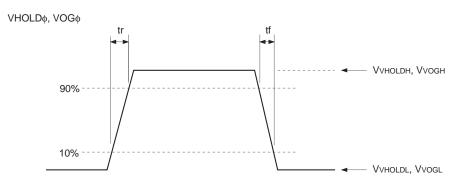
Assuming VRGH is the minimum value during the interval twh, then:

 $V\phi RG = VRGH - VRGL$

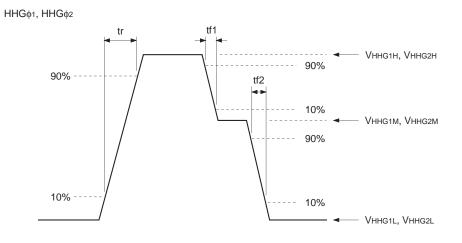
(5) Substrate clock waveform



(6) Vertical final stage accumulation clock waveform · Vertical final stage transfer clock waveform



(7) Inter-horizontal register transfer clock waveform



| | ltem | Sumbol | twh | | | twl | | | tr | | tf, | tf1, t | f2 | Unit | Remarks | |
|---------------------------|-------------------------|--------------------|------|------|------|------|------|------|------|------|------|--------|------|------|---------|------------------------|
| | nem | Symbol | Min. | Тур. | Max. | Min. | Тур. | Max. | Min. | Тур. | Max. | Min. | Тур. | Max. | Unit | Remarks |
| Re | eadout clock | Vτ | 2.3 | 2.5 | | | | | | 0.5 | | | 0.5 | | μs | During readout |
| · · | ertical transfer ock | Vφ1, Vφ2, Vφ3 | | | | | | | | | | 15 | | 350 | ns | *1 |
| clock | During imaging | Hφ1 | 24 | 29 | | 26 | 31 | | | 10 | 17.5 | | 10 | 17.5 | | *2 |
| Horizontal transfer clock | During imaging | Hø2 | 26 | 31 | | 24 | 29 | | | 10 | 15 | | 10 | 15 | ns | |
| ontal tr | During parallel- | Ηφı | | | | | | | | 0.01 | | | 0.01 | | | |
| Horizo | serial conversion | Hø2 | | | | | | | | 0.01 | | | 0.01 | | μs | |
| Re | eset gate clock | ¢ RG | 11 | 13 | | | 64 | | | 2 | | | 2 | | ns | |
| Sı | ubstrate clock | фSUB | 1.6 | 1.9 | | | | | | | 0.5 | | | 0.5 | μs | During drain charge |
| | ertical final stage | VHOLDø | | | | | | | | 20 | | | 20 | | ns | |
| | cumulation/ | VOGø | | | | | | | | 20 | | | 20 | | ns | |
| | ter-horizontal | HHGφ1 | | | | | | | | 20 | | | 20 | | ns | |
| | gister transfer ock | HHG _{\$2} | | | | | | | | 20 | | | 20 | | ns | |

Clock Switching Characteristics

*1 When vertical transfer clock driver CXD1268M is used.

| Itom | Symbol | | two | | Unit | Remarks | |
|---------------------------|----------|------|------|------|------|---------|--|
| Item | Symbol | Min. | Тур. | Max. | Unit | Remarks | |
| Horizontal transfer clock | Hφ1, Hφ2 | 24 | 29 | | ns | *3 | |

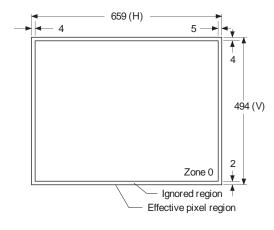
*3 The overlap period for twh and twl of horizontal transfer clocks H ϕ_1 and H ϕ_2 is two.

Image Sensor Characteristics

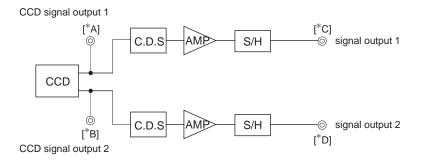
| Item | Symbol | Min. | Тур. | Max. | Unit | Measurement method | Remarks |
|------------------------------------|--------|------|-------|-------|------|-----------------------|-----------|
| Sensitivity | S | | 350 | | mV | 1 | |
| Saturation signal | Vsat | 500 | | | mV | 2 | Ta = 60°C |
| Smear | Sm | | 0.002 | 0.007 | % | 3 | |
| Video signal shading | SH | | | 25 | % | 4 | Zone 0 |
| Dark signal | Vdt | | | 2 | mV | 5 | Ta = 60°C |
| Dark signal shading | ΔVdt | | | 1 | mV | 6 | Ta = 60°C |
| Lag | Lag | | | 0.5 | % | 7 | |
| Uniformity between output channels | ΔV | | | 3 | % | 8 | |

Note) All the characteristic data of this image sensor was yielded when the sensor was operated in the 1/60s interlaced mode.

Zone Definition of Video Signal Shading



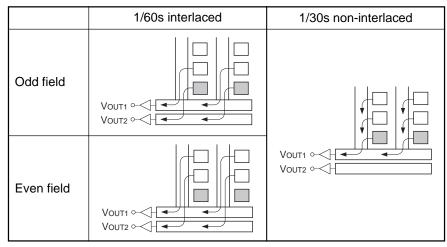
Measurement System



Note) Adjust the amplifier gain so that the gain between [*A] and [*C], and between [*B] and [*D] equals 1.

© Readout modes

The output methods for the two readout modes indicated below are now described.



1. 1/60s interlaced

In this mode, the signals are output in a 1/60s period using the two output pins (VOUT1, VOUT2). The signals from two adjacent horizontal lines are simultaneously output from the respective output pins. The lines output from the output pins are changed over with each field. The VOUT1 signal after it has passed through the CDS and other external circuits or the signal produced by adding the VOUT1 and VOUT2 signals accommodate interlaced scanning.

2. 1/30s non-interlaced

In this mode, the signals are output in a 1/30s period using only one output pin (Vout1). Unlike the 1/60s interlaced mode described above, the external circuit can be simplified. The imaging characteristics also differ from those of the other modes.

Image Sensor Characteristics Measurement Method

O Measurement conditions

- 1) In the following measurements, the substrate voltage is set to the value indicated on the device, and the device drive conditions are at the typical values of the bias and clock voltage conditions.
- 2) In the following measurements, spot blemishes are excluded and, unless otherwise specified, the optical black (OB) level is used as the reference for the signal output and the value measured at point [*A] in the measurement system is used.
- 3) In the following measurements, this image sensor is operated in 1/60s interlaced mode.

O Definition of standard imaging conditions

1) Standard imaging condition I:

Use a pattern box (luminance 706cd/m², color temperature of 3200K halogen source) as a subject. (Pattern for evaluation is not applicable.) Use a testing standard lens with CM500S (t = 1.00mm) as an IR cut filter and image at F8. The luminous intensity to the sensor receiving surface at this point is defined as the standard sensitivity testing luminous intensity.

2) Standard imaging condition II :

Image a light source (color temperature of 3200K) with a uniformity of brightness within 2% at all angles. Use a testing standard lens with CM500S (t = 1.00mm) as an IR cut filter. The luminous intensity is adjusted to the value indicated in each testing item by the lens diaphragm.

1. Sensitivity

Set to standard imaging condition I. After selecting the electronic shutter mode with a shutter speed of 1/250s, measure the signal output (Vs) at the center of the screen and substitute the value into the following formula.

$$S = Vs \times \frac{250}{60} [mV]$$

2. Saturation signal

Set to standard imaging condition II. After adjusting the luminous intensity to 10 times the intensity with average value of signal output, 150mV, measure the minimum value of the signal output.

3. Smear

Set to standard imaging condition II. With the lens diaphragm at F5.6 to F8, adjust the luminous intensity to 500 times the intensity with average value of signal output, 150mV. When the readout clock is stopped and the charge drain is executed by the electronic shutter at the respective H blankings, measure the maximum value VSm [mV] of the signal output and substitute the value into the following formula.

$$Sm = \frac{VSm}{150} \times \frac{1}{500} \times \frac{1}{10} \times 100 [\%] (1/10V \text{ method conversion value})$$

4. Video signal shading

Set to standard imaging condition II. With the lens diaphragm at F5.6 to F8, adjust the luminous intensity so that the average value of the signal output is 150mV. Then measure the maximum (Vmax [mV]) and minimum (Vmin [mV]) values of the signal output and substitute the values into the following formula.

 $SH = (Vmax - Vmin)/150 \times 100 [\%]$

5. Dark signal

Measure the average value of the signal output (Vdt [mV]) with the device ambient temperature 60°C and the device in the light-obstructed state, using the horizontal idle transfer level as a reference.

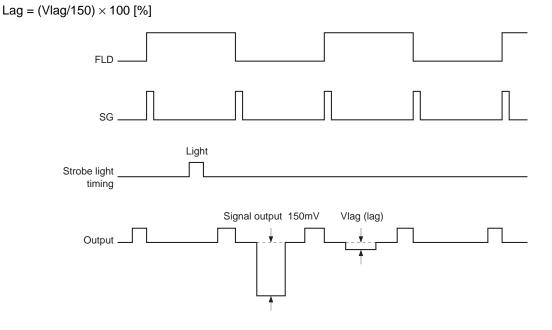
6. Dark signal shading

After measuring 5, measure the maximum (Vdmax [mV]) and minimum (Vdmin [mV]) values of the dark signal output and substitute the values into the following formula.

 $\Delta V dt = V dmax - V dmin [mV]$

7. Lag

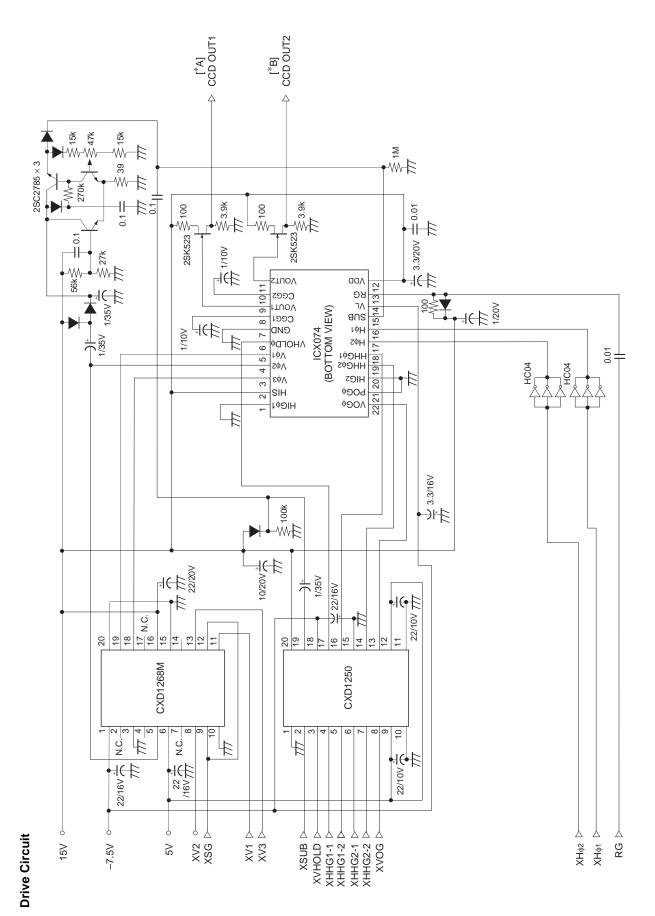
Adjust the signal output value generated by strobe light to 150mV. After setting the strobe light so that it strobes with the following timing, measure the residual signal (Vlag). Substitute the value into the following formula.



8. Uniformity between output channels

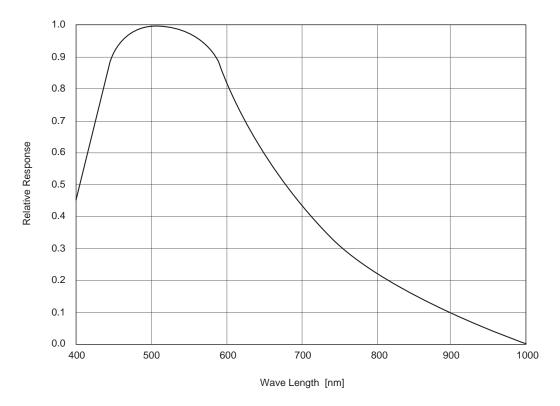
Set to standard imaging condition I. Measure the signals at signal output 1 (V1) and at signal output 2 (V2), and substitute the values into the following formula.

$$\Delta V = \frac{|V2 - V1|}{V1} \times 100 \,[\%]$$



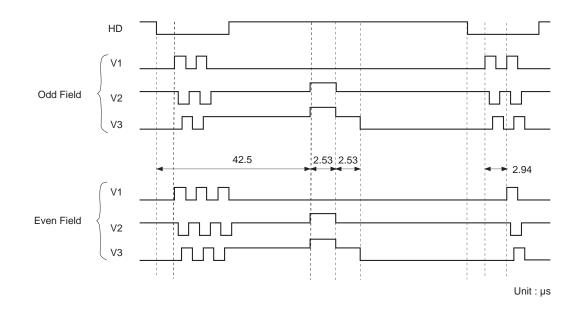
Spectral Sensitivity Characteristics

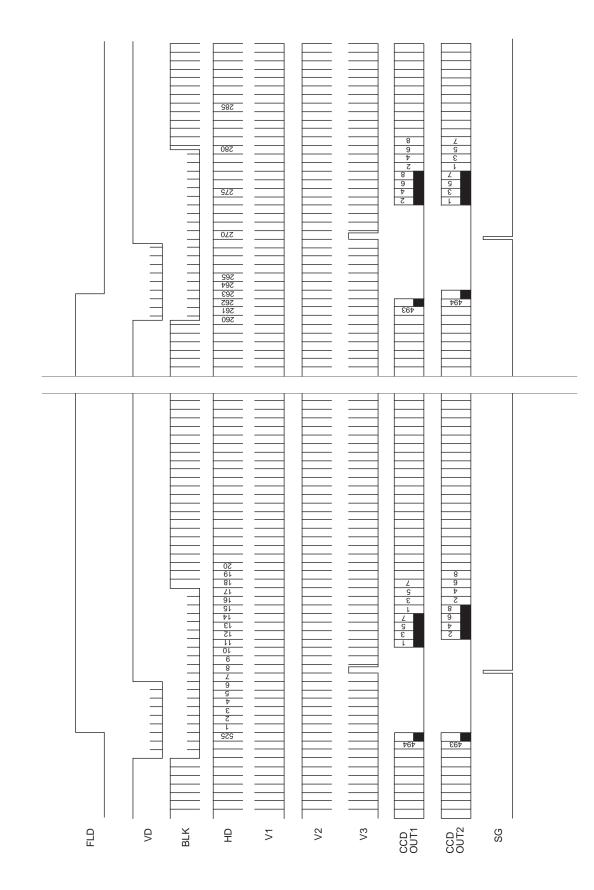
(includes lens characteristics, excludes light source characteristics)





1/60s interlaced mode





SONY

SUB

1/60s interlaced mode

Drive Timing Chart (Horizontal Sync)

Notes on Handling

1) Static charge prevention

CCD image sensors are easily damaged by static discharge. Before handling be sure to take the following protective measures.

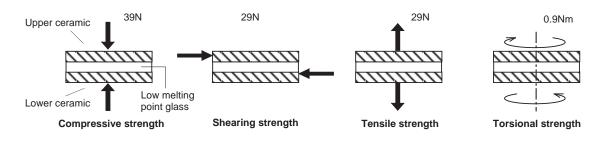
- a) Either handle bare handed or use non-chargeable gloves, clothes or material.
 - Also use conductive shoes.
- b) When handling directly use an earth band.
- c) Install a conductive mat on the floor or working table to prevent the generation of static electricity.
- d) lonized air is recommended for discharge when handling CCD image sensor.
- e) For the shipment of mounted substrates, use boxes treated for the prevention of static charges.

2) Soldering

- a) Make sure the package temperature does not exceed 80°C.
- b) Solder dipping in a mounting furnace causes damage to the glass and other defects. Use a ground 30W soldering iron and solder each pin in less than 2 seconds. For repairs and remount, cool sufficiently.
- c) To dismount an image sensor, do not use a solder suction equipment. When using an electric desoldering tool, use a thermal controller of the zero cross On/Off type and connect it to ground.
- 3) Dust and dirt protection

Image sensors are packed and delivered by taking care of protecting its glass plates from harmful dust and dirt. Clean glass plates with the following operation as required, and use them.

- a) Perform all assembly operations in a clean room (class 1000 or less).
- b) Do not either touch glass plates by hand or have any object come in contact with glass surfaces. Should dirt stick to a glass surface, blow it off with an air blower. (For dirt stuck through static electricity ionized air is recommended.)
- c) Clean with a cotton bud and ethyl alcohol if the grease stained. Be careful not to scratch the glass.
- d) Keep in a case to protect from dust and dirt. To prevent dew condensation, preheat or precool when moving to a room with great temperature differences.
- e) When a protective tape is applied before shipping, just before use remove the tape applied for electrostatic protection. Do not reuse the tape.
- 4) Installing (attaching)
 - a) Remain within the following limits when applying a static load to the package. Do not apply any load more than 0.7mm inside the outer perimeter of the glass portion, and do not apply any load or impact to limited portions. (This may cause cracks in the package.)

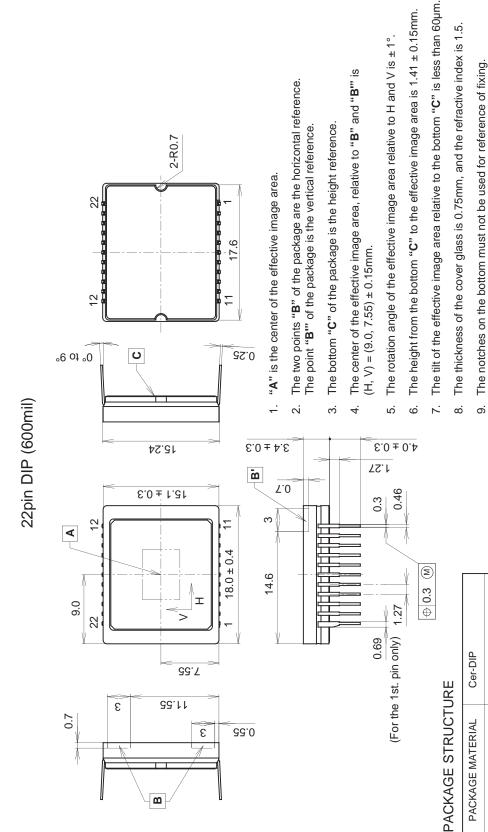


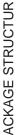
b) If a load is applied to the entire surface by a hard component, bending stress may be generated and the package may fracture, etc., depending on the flatness of the ceramic portions. Therefore, for installation, use either an elastic load, such as a spring plate, or an adhesive.

- c) The adhesive may cause the marking on the rear surface to disappear, especially in case the regulated voltage value is indicated on the rear surface. Therefore, the adhesive should not be applied to this area, and indicated values should be transferred to other locations as a precaution.
- d) The upper and lower ceramic are joined by low melting point glass. Therefore, care should be taken not to perform the following actions as this may cause cracks.
 - Applying repeated bending stress to the outer leads.
 - Heating the outer leads for an extended period with a soldering iron.
 - Rapidly cooling or heating the package.
 - Applying any load or impact to a limited portion of the low melting point glass using tweezers or other sharp tools.
 - Prying at the upper or lower ceramic using the low melting point glass as a fulcrum.
 - Note that the same cautions also apply when removing soldered products from boards.
- e) Acrylate anaerobic adhesives are generally used to attach CCD image sensors. In addition, cyanoacrylate instantaneous adhesives are sometimes used jointly with acrylate anaerobic adhesives. (reference)

5) Others

- a) Do not expose to strong light (sun rays) for long periods. For continuous using under cruel condition exceeding the normal using condition, consult our company.
- b) Exposure to high temperature or humidity will affect the characteristics. Accordingly avoid storage or usage in such conditions.





| PACKAGE MATERIAL | Cer-DIP |
|------------------|-------------|
| LEAD TREATMENT | TIN PLATING |
| LEAD MATERIAL | 42 ALLOY |
| PACKAGE WEIGHT | 2.6g |
| | |

Unit: mm

Package Outline